UTC UNISONIC TECHNOLOGIES CO., LTD

BC846AS

Preliminary

DUAL TRANSISTOR

DUAL NPN SURFACE MOUNT SMALL SIGNAL TRANSISTOR

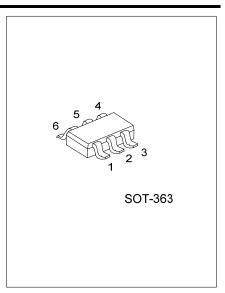
DESCRIPTION

The UTC BC846AS is a dual NPN surface mount small signal transistor, it uses UTC's advanced technology to provide customers with high DC current gain, etc.

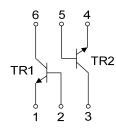
The UTC BC846AS is suitable for switching and AF amplifier applications.



- * Suitable for automatic insertion in thick and thin-film circuits
- * Switching and AF Amplifier Applications



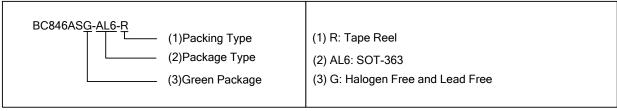
EQUIVALENT CIRCUIT



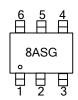
ORDERING INFORMATION

Ordering Number	Package	Pin Assignment						Doolsing	
Ordering Number		1	2	3	4	5	6	Packing	
BC846ASG-AL6-R	SOT-363	E1	B1	C2	E2	B2	C1	Tape Reel	

Note: Pin Assignment: E: Emitter B: Base C: Collector



MARKING



www.unisonic.com.tw 1 of 3

■ **ABSOLUTE MAXIMUM RATINGS** (T_A=25°C unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	V_{CBO}	80	V
Collector-Emitter Voltage	V_{CEO}	65	V
Emitter-Base Voltage	V_{EBO}	6	V
Collector Current	Ic	100	mA
Peak Collector Current	I _{CM}	200	mA
Peak Emitter Current	I _{EM}	200	mA
Power Dissipation	P_{D}	325	mW
Operating Temperature Range	T_J	-40 ~ +150	°C
Storage Temperature	T _{STG}	-40 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ_{JA}	384.6	°C/W

Note: Device mounted on FR-4 PCB minimum land pad.

■ **ELECTRICAL CHARACTERISTICS** (T_A =25°C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
OFF CHARACTERISTICS								
Collector-Base Breakdown Voltage	V _{(BR)CBO}	I _C =10μA, I _B =0	80			V		
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C =10mA, I _B =0	65			V		
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	I _E =1μA, I _C =0	6			V		
ON CHARACTERISTICS								
DC Current Gain	h _{FE}	V _{CE} =5.0V, I _C =2.0mA	110		220			
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I _C =10mA, I _B =0.5mA		90	250	mV		
		I _C =100mA, I _B =5.0mA		200	600	mV		
Base-Emitter Saturation Voltage	V _{BE(SAT)}	I _C =10mA, I _B =0.5mA		700		mV		
		I _C =100mA, I _B =5.0mA		900		mV		
Base-Emitter Voltage	V _{BE(ON)}	V_{CE} =5.0V, I_{C} =2.0mA	580	660	700	mV		
		V _{CE} =5.0V, I _C =10mA			770	mV		
SMALL SIGNAL CHARACTERISTICS								
Collector-Cutoff Current	I _{CES}	V _{CE} =80V			15	nA		
	I _{CBO}	V _{CB} =40V			15	nA		
		V _{CB} =30V, T _A =150°C			5	μΑ		
Gain Bandwidth Product	f _T	V _{CE} =5.0V, I _C =10mA, f=100MHz	100			MHz		
Collector-Base Capacitance	C _{CB}	V _{CB} =10V, f=1.0MHz		2		pF		

Note: Short duration pulse test used to minimize self-heating effect.

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.

